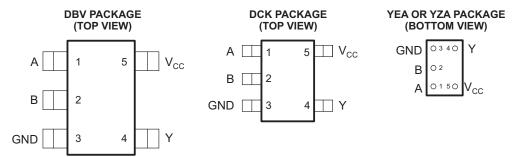
www.ti.com

SCES389H-MARCH 2002-REVISED JUNE 2006

#### **FEATURES**

- Available in the Texas Instruments
   NanoStar<sup>™</sup> and NanoFree<sup>™</sup> Packages
- Optimized for 1.8-V Operation and Is 3.6-V I/O Tolerant to Support Mixed-Mode Signal Operation
- I<sub>off</sub> Supports Partial Power-Down-Mode Operation
- Sub-1-V Operable
- Max t<sub>pd</sub> of 2.5 ns at 1.8 V
- Low Power Consumption, 10-μA Max I<sub>CC</sub>

- ±8-mA Output Drive at 1.8 V
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)
  - 1000-V Charged-Device Model (C101)



See mechanical drawings for dimensions.

#### DESCRIPTION/ORDERING INFORMATION

This single 2-input exclusive-OR gate is operational at 0.8-V to 2.7-V  $V_{CC}$ , but is designed specifically for 1.65-V to 1.95-V  $V_{CC}$  operation.

The SN74AUC1G86 performs the Boolean function  $Y = A \oplus B$  or  $Y = \overline{AB} + A\overline{B}$  in positive logic.

A common application is as a true/complement element. If the input is low, the other input is reproduced in true form at the output. If the input is high, the signal on the other input is reproduced inverted at the output.

NanoStar<sup>™</sup> and NanoFree<sup>™</sup> package technology is a major breakthrough in IC packaging concepts, using the die as the package.

This device is fully specified for partial-power-down applications using  $I_{off}$ . The  $I_{off}$  circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

### **ORDERING INFORMATION**

T <sub>A</sub>	PACKAGE <sup>(1)</sup>		ORDERABLE PART NUMBER	TOP-SIDE MARKING <sup>(2)</sup>
	NanoStar™ WCSP (DSBGA) – YEA	Reel of 3000	SN74AUC1G86YEAR	III
-40°C to 85°C	NanoFree <sup>™</sup> WCSP (DSBGA) – YZA (Pb-free)	Reel of 3000	SN74AUC1G86YZAR	UH_
	SOT (SOT-23) - DBV	Reel of 3000	SN74AUC1G86DBVR	U86_
	SOT (SC-70) - DCK	Reel of 3000	SN74AUC1G86DCKR	UH_

<sup>(1)</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

<sup>(2)</sup> DBV/DCK: The actual top-side marking has one additional character that designates the assembly/test site. YEA/YZA: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate the assembly/test site.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

NanoStar, NanoFree are trademarks of Texas Instruments.

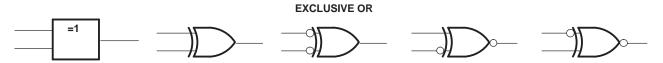


#### **FUNCTION TABLE**

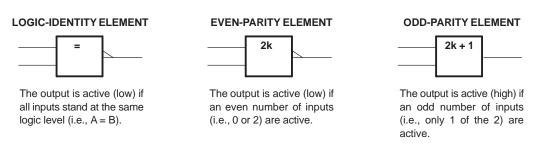
INPU	OUTPUT		
Α	В	Y	
L	L	L	
L	Н	Н	
Н	L	Н	
Н	Н	L	

### **EXCLUSIVE-OR LOGIC**

An exclusive-OR gate has many applications, some of which can be represented better by alternative logic symbols.



These are five equivalent exclusive-OR symbols valid for an SN74AUC1G86 gate in positive logic; negation may be shown at any two ports.



### Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
$V_{CC}$	Supply voltage range		-0.5	3.6	V
VI	Input voltage range (2)		-0.5	3.6	V
Vo	Voltage range applied to any output in the I	high-impedance or power-off state <sup>(2)</sup>	-0.5	3.6	V
Vo	Output voltage range <sup>(2)</sup>		-0.5	V <sub>CC</sub> + 0.5	V
I <sub>IK</sub>	Input clamp current	V <sub>I</sub> < 0		-50	mA
I <sub>OK</sub>	Output clamp current $V_O < 0$			-50	mA
Io	Continuous output current			±20	mA
	Continuous current through V <sub>CC</sub> or GND			±100	mA
		DBV package		206	
$\theta_{JA}$	Package thermal impedance (3)	DCK package		252	°C/W
		YEA/YZA package		154	
T <sub>stq</sub>	Storage temperature range		-65	150	°C

<sup>(1)</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

<sup>(2)</sup> The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

<sup>(3)</sup> The package thermal impedance is calculated in accordance with JESD 51-7.

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## **Recommended Operating Conditions**(1)

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage		0.8	2.7	V
		V <sub>CC</sub> = 0.8 V	V <sub>CC</sub>		
$V_{IH}$	High-level input voltage	V <sub>CC</sub> = 1.1 V to 1.95 V	$0.65 \times V_{CC}$		V
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.7		
		V <sub>CC</sub> = 0.8 V		0	
$V_{IL}$	Low-level input voltage	V <sub>CC</sub> = 1.1 V to 1.95 V		$0.35 \times V_{CC}$	V
		V <sub>CC</sub> = 2.3 V to 2.7 V		0.7	
V <sub>I</sub>	Input voltage		0	3.6	V
Vo	Output voltage		0	V <sub>CC</sub>	V
		V <sub>CC</sub> = 0.8 V		-0.7	
		V <sub>CC</sub> = 1.1 V		-3	
$I_{OH}$	High-level output current	n-level output current $V_{CC} = 1.4 \text{ V}$		<b>-</b> 5	mA
		V <sub>CC</sub> = 1.65 V		-8	
		V <sub>CC</sub> = 2.3 V		-9	
		V <sub>CC</sub> = 0.8 V		0.7	
		V <sub>CC</sub> = 1.1 V		3	
$I_{OL}$	Low-level output current	V <sub>CC</sub> = 1.4 V		5	mA
		V <sub>CC</sub> = 1.65 V		8	
		V <sub>CC</sub> = 2.3 V		9	
Δt/Δν	Input transition rise or fall rate			20	ns/V
T <sub>A</sub>	Operating free-air temperature		-40	85	°C

<sup>(1)</sup> All unused inputs of the device must be held at  $V_{CC}$  or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

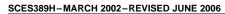
#### **Electrical Characteristics**

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V <sub>cc</sub>	MIN	TYP <sup>(1)</sup>	MAX	UNIT
	I <sub>OH</sub> = -100 μA	0.8 V to 2.7 V	V <sub>CC</sub> - 0.1			
	$I_{OH} = -0.7 \text{ mA}$	0.8 V		0.55		
\/	$I_{OH} = -3 \text{ mA}$	1.1 V	0.8			V
V <sub>OH</sub>	$I_{OH} = -5 \text{ mA}$	1.4 V	1			V
	$I_{OH} = -8 \text{ mA}$	1.65 V	1.2			
	$I_{OH} = -9 \text{ mA}$	2.3 V	1.8			
	$I_{OL} = 100 \mu A$	0.8 V to 2.7 V			0.2	
	$I_{OL} = 0.7 \text{ mA}$	0.8 V		0.25		
N/	$I_{OL} = 3 \text{ mA}$	1.1 V			0.3	V
V <sub>OL</sub>	I <sub>OL</sub> = 5 mA	1.4 V			0.4	V
	I <sub>OL</sub> = 8 mA	1.65 V			0.45	
	I <sub>OL</sub> = 9 mA	2.3 V			0.6	
I <sub>I</sub> A or B input	$V_I = V_{CC}$ or GND	0 to 2.7 V			±5	μΑ
I <sub>off</sub>	$V_I$ or $V_O = 2.7 \text{ V}$	0			±10	μΑ
I <sub>cc</sub>	$V_I = V_{CC}$ or GND, $I_O = 0$	0.8 V to 2.7 V			10	μΑ
C <sub>i</sub>	V <sub>I</sub> = V <sub>CC</sub> or GND	2.5 V		2.5		pF

<sup>(1)</sup> All typical values are at  $T_A = 25$ °C.

## SN74AUC1G86 SINGLE 2-INPUT EXCLUSIVE-OR GATE





### **Switching Characteristics**

over recommended operating free-air temperature range,  $C_L = 15 \text{ pF}$  (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = 0.8 V	V <sub>CC</sub> = 1 ± 0.1		V <sub>CC</sub> = ± 0.	1.5 V 1 V		c = 1.8 0.15 \		V <sub>CC</sub> = 1 ± 0.2		UNIT	
	(INFUT)	(OUTPUT)	TYP	MIN	MAX	MIN	MIN MAX	MIN	TYP	MAX	MIN	MAX		
	Α	V	5.5	0.8	3.8	0.5	2.6	0.4	1	1.7	0.3	1.3	20	
t <sub>pd</sub>	t <sub>pd</sub>	В	ř	5	0.8	3.8	0.5	2.6	0.4	1	1.7	0.3	1.2	ns

## **Switching Characteristics**

over recommended operating free-air temperature range,  $C_L = 30 \text{ pF}$  (unless otherwise noted) (see Figure 1)

	PARAMETER	FROM (INPUT)	TO (OUTPUT)	V	<sub>CC</sub> = 1.8 ± 0.15 V	V	V <sub>CC</sub> = 2 ± 0.2		UNIT
		(INPOT)	(001F01)	MIN	TYP	MAX	MIN	MAX	
Ī		A	V	0.8	1.5	2.6	0.7	2	
	τ <sub>pd</sub>	В	Y	0.8	1.5	2.6	0.7	2	ns

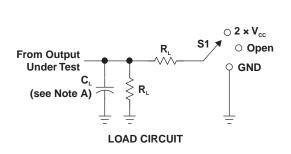
## **Operating Characteristics**

 $T_A = 25^{\circ}C$ 

	PARAMETER	TEST	V <sub>CC</sub> = 0.8 V	V <sub>CC</sub> = 1.2 V	V <sub>CC</sub> = 1.5 V	V <sub>CC</sub> = 1.8 V	V <sub>CC</sub> = 2.5 V	UNIT
	FARAMETER	CONDITIONS	TYP	TYP	TYP	TYP	TYP	ONIT
$C_{pd}$	Power dissipation capacitance	f = 10 MHz	16	16	16.5	17	18.5	pF

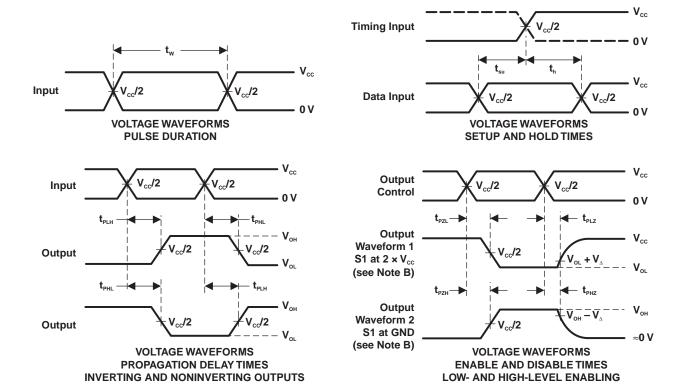


### PARAMETER MEASUREMENT INFORMATION



TEST	<b>S</b> 1
t <sub>PLH</sub> /t <sub>PHL</sub>	Open
t <sub>PLZ</sub> /t <sub>PZL</sub>	2 × V <sub>cc</sub>
t <sub>PHZ</sub> /t <sub>PZH</sub>	GND

V <sub>cc</sub>	<b>C</b> ∟	$R_{\scriptscriptstyle L}$	$V_{\scriptscriptstyle \Delta}$
0.8 V	15 pF	<b>2 k</b> Ω	0.1 V
1.2 V $\pm$ 0.1 V	15 pF	<b>2 k</b> Ω	0.1 V
1.5 V $\pm$ 0.1 V	15 pF	<b>2 k</b> Ω	0.1 V
1.8 V $\pm$ 0.15 V	15 pF	<b>2 k</b> Ω	0.15 V
2.5 V $\pm$ 0.2 V	15 pF	<b>2 k</b> Ω	0.15 V
1.8 V $\pm$ 0.15 V	30 pF	<b>1 k</b> Ω	0.15 V
2.5 V $\pm$ 0.2 V	30 pF	<b>500</b> Ω	0.15 V



NOTES: A.  $C_L$  includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators have the following characteristics: PRR  $\leq$  10 MHz,  $Z_o = 50 \Omega$ , slew rate  $\geq$  1 V/ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
- F.  $t_{\mbox{\tiny PZL}}$  and  $t_{\mbox{\tiny PZH}}$  are the same as  $t_{\mbox{\tiny en}}$ .
- G.  $t_{\text{PLH}}$  and  $t_{\text{PHL}}$  are the same as  $t_{\text{od}}$ .
- H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms





.com 6-Dec-2006

#### PACKAGING INFORMATION

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
SN74AUC1G86DBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUC1G86DBVRE4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUC1G86DCKR	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUC1G86DCKRE4	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AUC1G86YEAR	NRND	WCSP	YEA	5	3000	TBD	SNPB	Level-1-260C-UNLIM
SN74AUC1G86YEPR	NRND	WCSP	YEP	5	3000	TBD	SNPB	Level-1-260C-UNLIM
SN74AUC1G86YZAR	NRND	WCSP	YZA	5	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM
SN74AUC1G86YZPR	ACTIVE	WCSP	YZP	5	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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# DBV (R-PDSO-G5)

## PLASTIC SMALL-OUTLINE PACKAGE



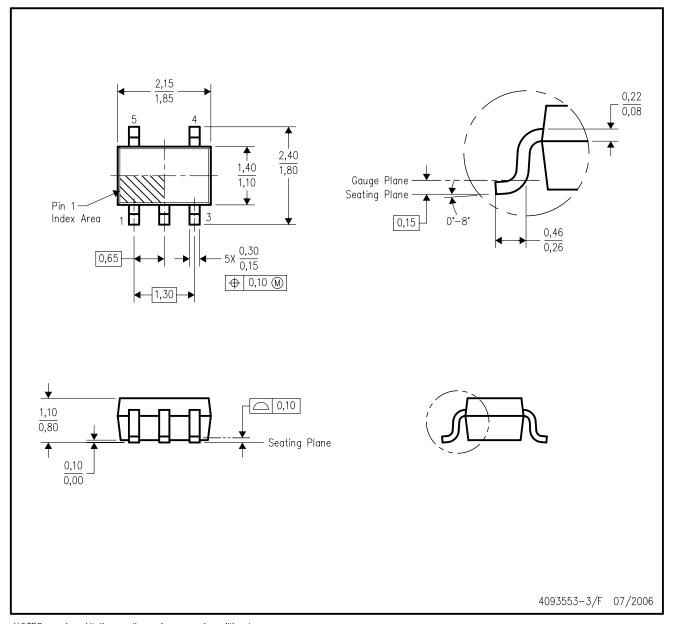
NOTES:

- A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
- D. Falls within JEDEC MO-178 Variation AA.



# DCK (R-PDSO-G5)

# PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
- D. Falls within JEDEC MO-203 variation AA.



# YEA (R-XBGA-N5)

## DIE-SIZE BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters.

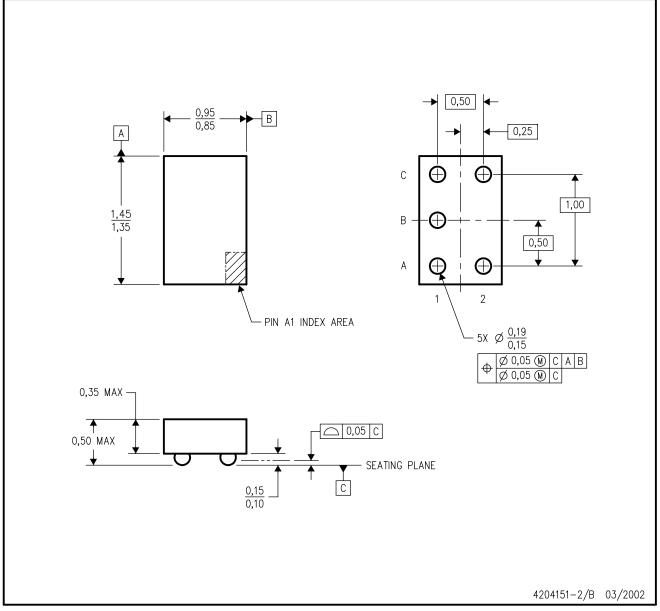
- B. This drawing is subject to change without notice.
- C. NanoStar  $\mathbf{M}$  package configuration.
- D. Package complies to JEDEC MO-211 variation EA.
- E. This package is tin-lead (SnPb). Refer to the 5 YZA package (drawing 4204151) for lead-free.

NanoStar is a trademark of Texas Instruments.



# YZA (R-XBGA-N5)

## DIE-SIZE BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters.

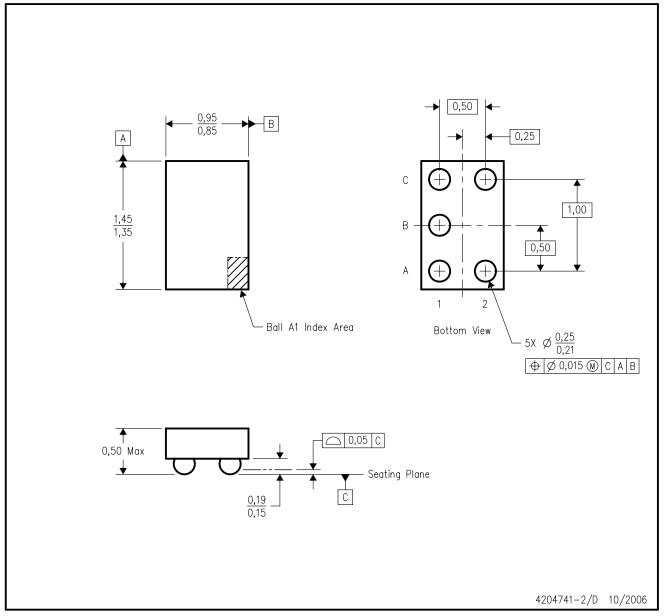
- B. This drawing is subject to change without notice.
- C. NanoFree  $^{\text{TM}}$  package configuration.
- D. Package complies to JEDEC MO-211 variation EA.
- E. This package is lead-free. Refer to the 5 YEA package (drawing 4203167) for tin-lead (SnPb).

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# YZP (R-XBGA-N5)

## DIE-SIZE BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. NanoFree  $^{\text{TM}}$  package configuration.
- D. This package is lead-free. Refer to the 5 YEP package (drawing 4204725) for tin-lead (SnPb).

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# YEP (R-XBGA-N5)

## DIE-SIZE BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. NanoStar  $\mathbf{M}$  package configuration.
- D. This package is tin-lead (SnPb). Refer to the 5 YZP package (drawing 4204741) for lead-free.

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